



Charged Particle Optics

Radovan Vašina





Application of charged particle optics

Charged particle optics is/was used in the following areas:

- Cathode ray tubes television, oscilloscopes, radars – obsolete
- **Electron and ion microscopes wavelength reduction to enhance resolution**
- Electron and ion lithographs
- Particle accelerators
- Plasma coating, microwave magnetron

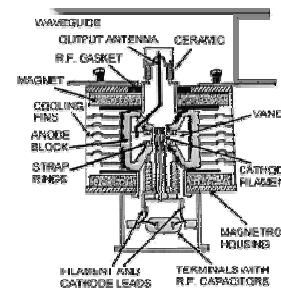


Figure 1 Sectional view of a typical magnetron
(Courtesy of Michael S. Wagner)



Comparison: Charged Particle and Light Optics

Feature	Charged Particle Optics	Analogy in Light Optics
Optical elements	Electrostatic and/or magnetic field	Glass and transparent materials
Optical axis must be	Vacuum	Transparent
Lenses	Variable focus	Fixed focus
Focusing	Changing field strength	Moving lens or object Exchange lens
Deflection and scanning	Electrostatic and/or magnetic	Mechanical
Aberrations	Not correctable at round lenses	Easily correctable
Wavelength	~ 2 – 200 pm (electrons)	~ 200 – 1000 nm
Depth of focus	High	Low
Magnification	2x – 1000 000x	1x – 2000x
Maximum resolution	1 nm – 0.1 nm	500 nm

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie





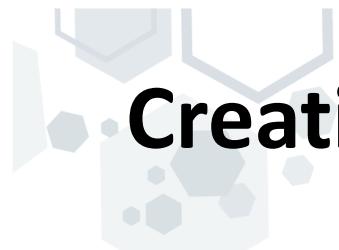
Overview of optical elements

Optical element	Charged particle optics	Analogy in Light Optics
Sources	Hairpin, Schottky emitter, CFEG	Arc lamp, laser, LEDs etc.
„Round“ lenses	Magnetostatic, electrostatic lens	Convergent, divergent lenses
Apertures	Round, annular, arrays	Many types
Deflectors	Magnetostatic, electrostatic	~ Prisms, gratings, mirrors
Multipoles	Magnetostatic, electrostatic	~ Cylindric lenses
Mirrors	Electrostatic	Concave, convex mirrors
Grids	Electrostatic	-
Immersion lens	Immersion lenses	Immersion objectives
Exotic	Wien filter, RF cavities	-

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie





Creation of a charged particle optics device

Mechanical design

Calculation of the fields

Calculations of the beam trajectories and optical properties

Optimization iterations to get the performance

Tolerancing

Models

Controlling software



Basic facts

Electron charge

$$e=1.602 \times 10^{-19} C$$

Electron mass

$$m_0=9.109 \times 10^{-31} kg$$

Proton/electron mass ratio

1826

Relativistic energy

$$E = \frac{m_0 c^2}{\sqrt{1 - \frac{v^2}{c^2}}}$$

Non-relativistic

$$E = |e\Phi| = \frac{1}{2} m v^2$$

Electron wavelength

$$\lambda = \frac{h}{p} = \frac{h}{\frac{m_0 v}{\sqrt{1 - \frac{v^2}{c^2}}}}$$

Non-relativistically

$$\lambda [nm] = \frac{1.2}{\sqrt{|e\Phi|}}$$

Device	Energy [keV]	Wavelength [m]
TEM	50 ÷ 1000	$5.46 \div 1.22 \times 10^{-12}$
SEM	1 ÷ 30	$38.6 \div 7.04 \times 10^{-12}$



Lorentz force

Force acting on a single particle in a electrostatic and magnetostatic fields

$$\frac{d}{dt} \left(\frac{m\vec{v}}{\sqrt{1 - \frac{v^2}{c^2}}} \right) = e(\vec{E} + \vec{v} \times \vec{B})$$

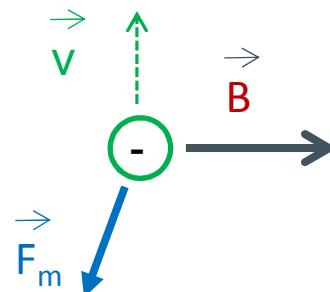
Electrostatic field - conservative

- Acts always on the particle
- Changes the particle energy and velocity
- Usage up to $\sim 30\text{kV}$
- Coulomb interaction among particles



Magnetostatic field – not conservative

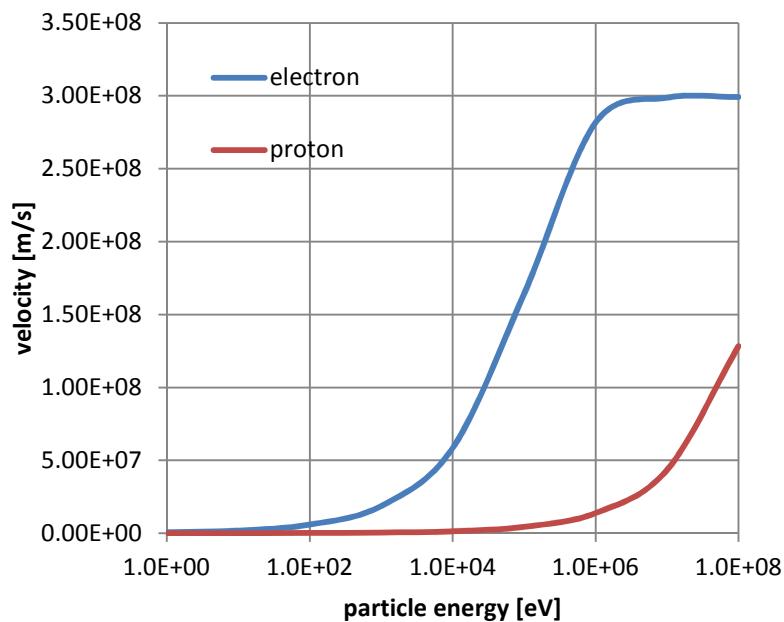
- Acts only on a moving particle
- Does not change energy of the particle
- Usage up to energies of GeV and more





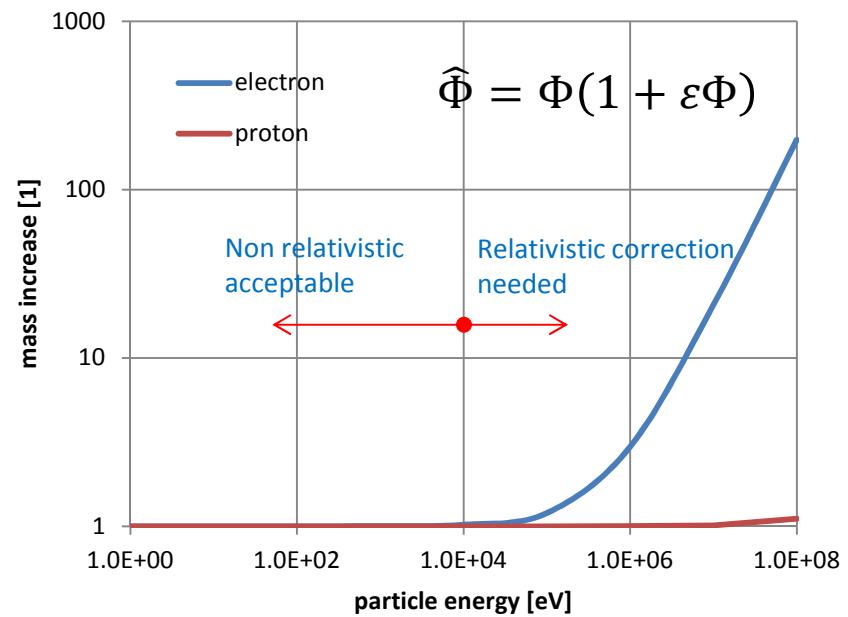
Relativistic effects

The relativistic effects can be neglected at ions



Explore. Discover. Resolve.

Usage of relativistic potential
beneficial for systems with no
electrostatic lenses



Vybrané partie z elektronové mikroskopie





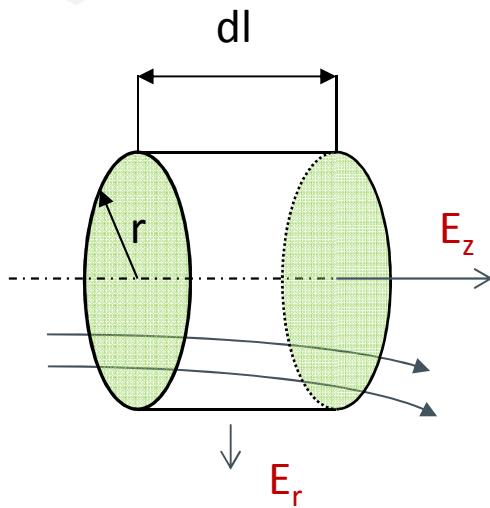
Paraxial approximation

The paradigm of the charged particle optics

Angles and lateral distances from the axis are small

Energy width is small

All higher orders in the potential and field series are neglected



$$\operatorname{div} \vec{E} = 0 \quad \oint d\vec{S} \vec{E} = 0$$

$$2\pi r E_r + \pi r^2 \left(E_z + \frac{\partial E_z}{\partial z} dl \right) - \pi r^2 E_z = 0$$

$$E_r = -\frac{r}{2} \frac{\partial E_z}{\partial z}$$

In an analogous way

$$B_r = -\frac{r}{2} \frac{\partial B_z}{\partial z}$$

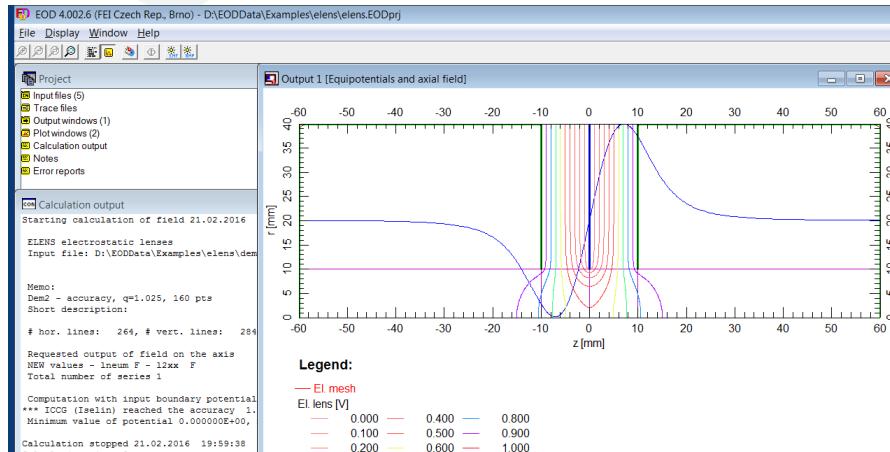
Linearity of the field only near to the optical axis

Vybrané partie z elektronové mikroskopie



Determination of the field (in cylindrical CS)

EOD J.Zlámal&B.Lencová



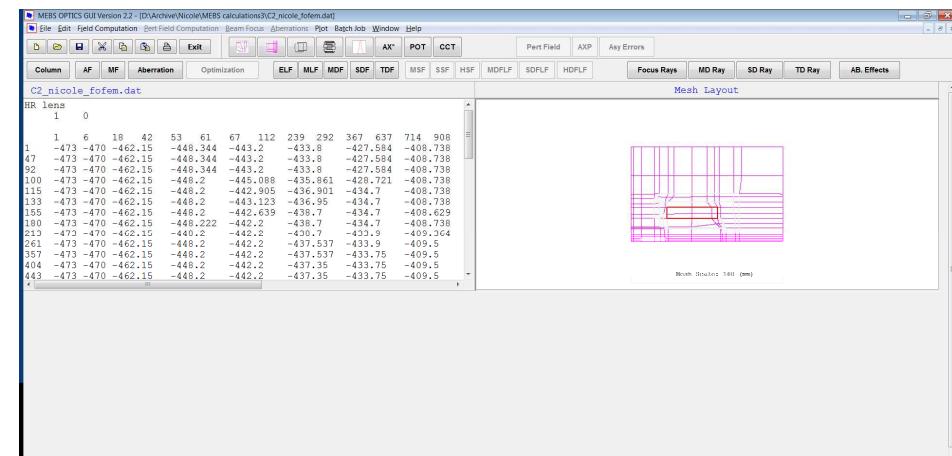
FEM with linear elements

Finite difference methods Simion
FEM 3D Ansys, Comsol, CST
Boundary element methods

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie

MEBS E.Munro&J.Rouse



FEM with quadratic elements

Symmetry *n*

Symmetry n of the field with optical elements: $2n$ multipoles

$n = 0$ Round lenses - focusing

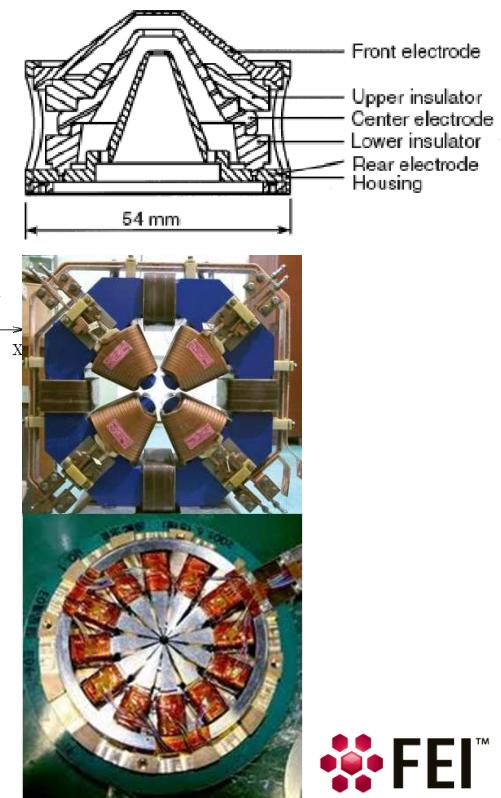
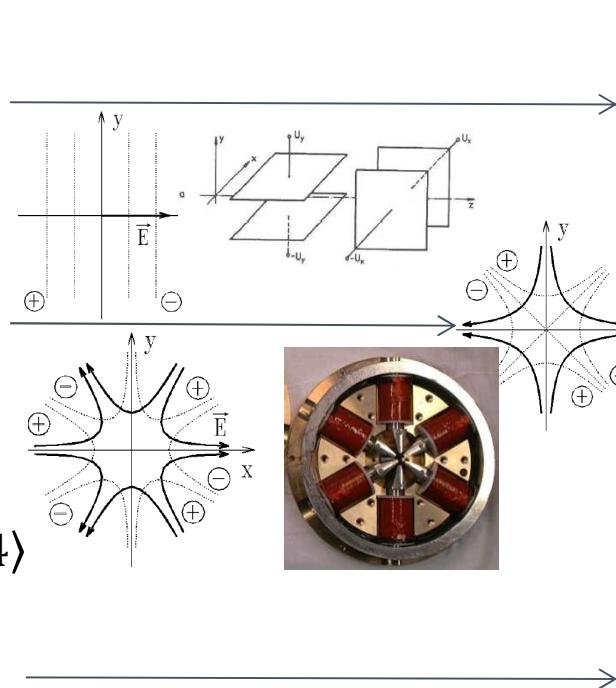
$n = 1$ Dipoles – deflectors

$n = 2$ Quadrupoles - stigmators

$n = 3$ Hexapoles - correctors

$n = 4$ Octopoles – universal $n \in \langle 1,4 \rangle$

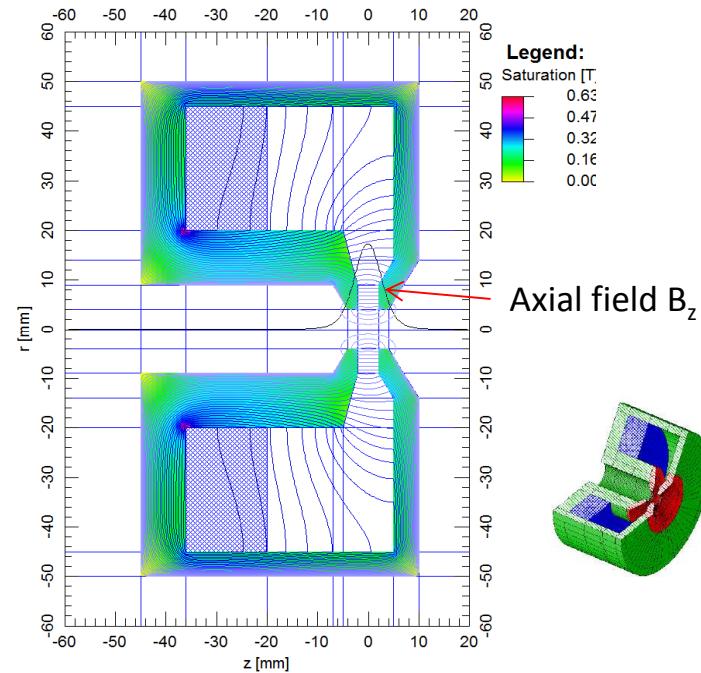
$n > 4$ Multipoles - correctors



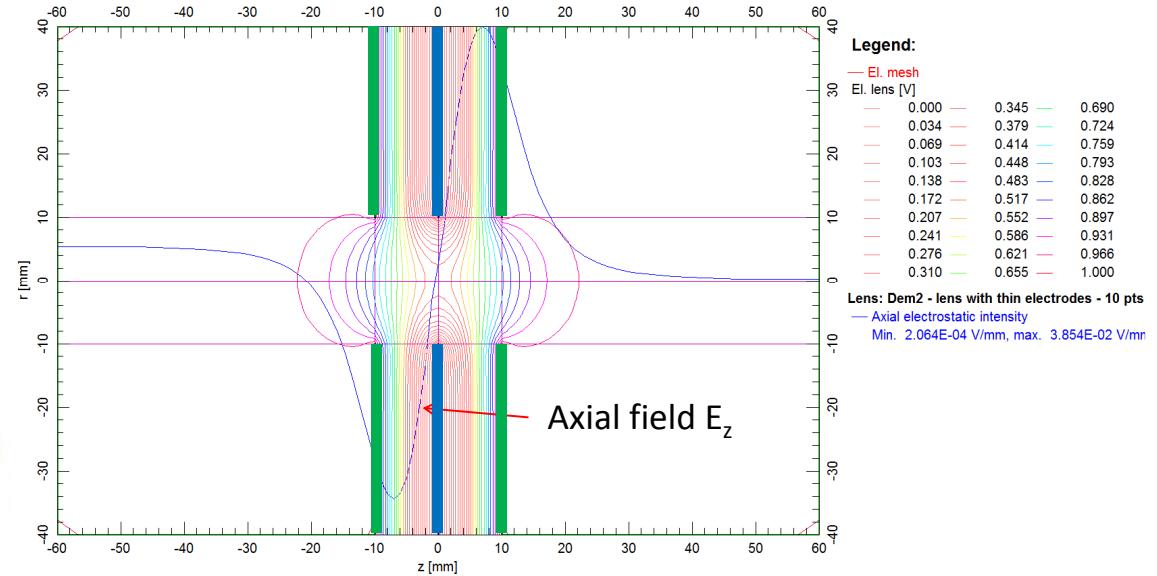


Axisymmetrical fields ($n=0$)

Magnetic field of a round lens



Electrostatic field of a round unipotential lens



Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie



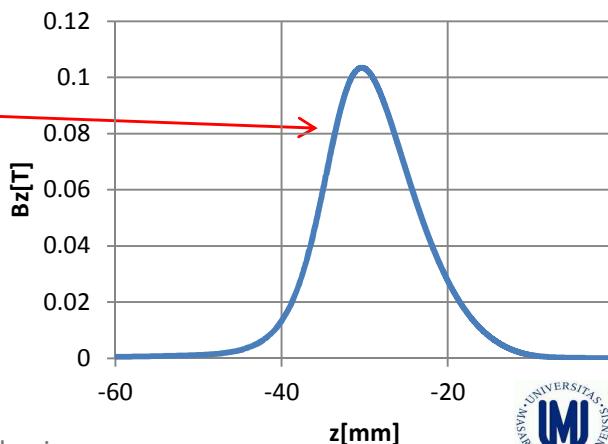
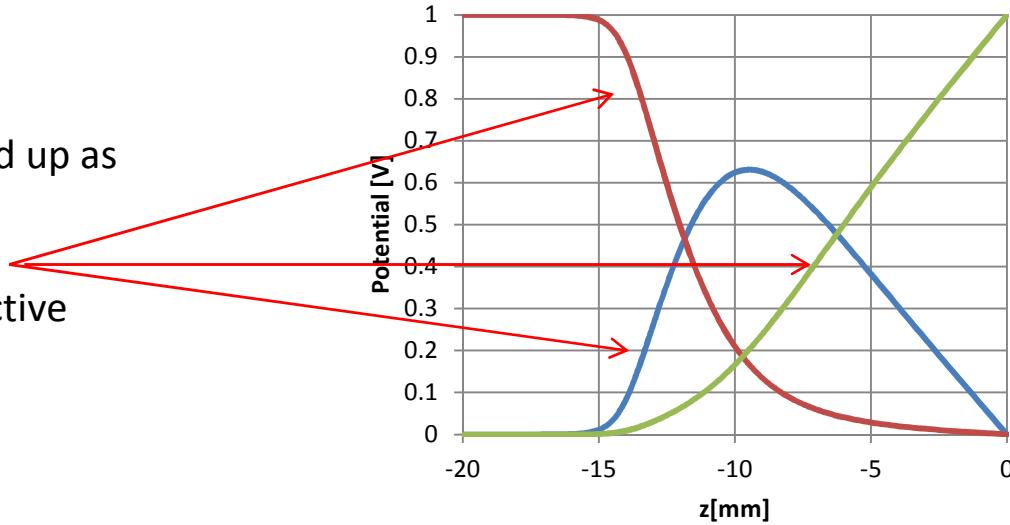
Axial fields

Total electrostatic field can be summed up as a weighted sum of the contribution of particular electrodes

Assigning the voltages to the respective electrodes

- Magnetostatic field
 - Axial field
- Deflector magnetostatic field
 - Axial field

Assigning the currents to the respective coils calculated with excitation $1A * \text{Number of turns}$





Equation of motion

Time dependent

$$m\vec{a} = q(\vec{E} + \vec{v} \times \vec{B})$$

$$m_0 \frac{d}{dt} \left(\frac{\vec{v}}{\sqrt{1 - \frac{v^2}{c^2}}} \right) = q(\vec{E} + \vec{v} \times \vec{B})$$

Relativistically corrected potential for electrons

$$\hat{\Phi} = \Phi(1 + \varepsilon\Phi) \quad \varepsilon = \frac{|e|}{2mc^2} \quad \eta = \sqrt{\frac{|e|}{2m}}$$

Time independent

$$\frac{d}{dz} \left[\sqrt{\frac{\hat{\Phi}}{1 + x'^2 + y'^2}} x' \right] = - \left(\frac{1}{2} + \varepsilon\Phi \right) \sqrt{\frac{1 + x'^2 + y'^2}{\hat{\Phi}}} E_x + \eta(B_y - y'B_z)$$

$$\frac{d}{dz} \left[\sqrt{\frac{\hat{\Phi}}{1 + x'^2 + y'^2}} y' \right] = - \left(\frac{1}{2} + \varepsilon\Phi \right) \sqrt{\frac{1 + x'^2 + y'^2}{\hat{\Phi}}} E_y + \eta(-B_x + x'B_z)$$

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie





Integration methods

The initial value problem $\dot{y} = f(t, y)$ $y(t_0) = y_0$

Runge Kutta

$$k_{1i} = h f(t_n, y_{ni})$$

$$k_{2i} = h f(t_n + a_2 h, y_{ni} + b_{21} k_{1i})$$

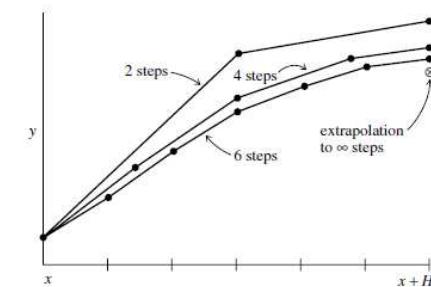
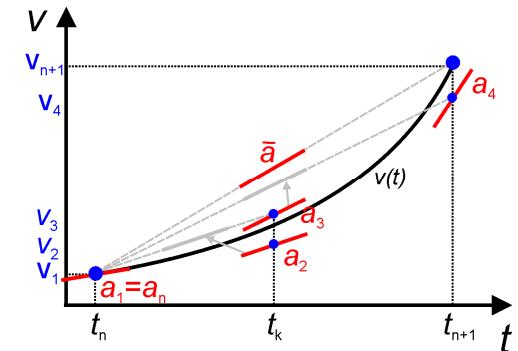
...

$$k_{6i} = h f(t_n + a_6 h, y_{ni} + b_{61} k_{1i} + \dots + b_{65} k_{5i})$$

$$y_{(n+1)i} = y_{ni} + c_1 k_{1i} + c_2 k_{2i} + c_3 k_{3i} + c_4 k_{4i} + c_5 k_{5i} + c_6 k_{6i} + O(h^6)$$

Bulirsch Stoer

- Richardson extrapolation $h \rightarrow 0$
- Using rational functions for extrapolation
- Error function of the integrator dependent on h^2





Interpolation

A general problem: The value of the field known only at discrete points (FEM not BEM).
The integration routine needs to obtain the accurate field values at a general place.

Interpolation of the **axial** fields: paraxial approximation

- Cubic or quintic splines: cubic or quintic polynomials with continuous 2nd or 4th derivative
- Fourier Bessel series

$$B_z = \sum_{m=1}^M C_m \sin\left(\frac{m\pi z}{L}\right) I_0\left(\frac{m\pi r}{L}\right),$$

$$B_r = - \sum_{m=1}^M C_m \cos\left(\frac{m\pi z}{L}\right) I_1\left(\frac{m\pi r}{L}\right)$$

$$h_0(x) = \pi^{-0.25} \exp\left(-\frac{1}{2}x^2\right)$$

$$h_1(x) = \sqrt{2} x h_0(x)$$

$$h_i(x) = \left\{ \sqrt{2} x h_{i-1}(x) - \sqrt{i-1} h_{i-2}(x) \right\} / \sqrt{i}$$

- Hermite series



Interpolation

Interpolation of **general** data:

- Bicubic spline
- ZRP method – interpolation using Laplacian base functions

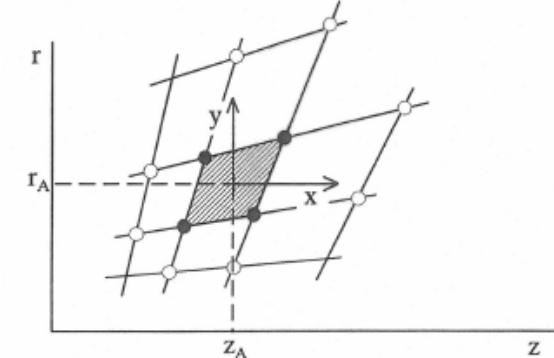
(author J.Chmelík)

Using a local coordinate system

$$x = z - z_A, \quad y = r - r_a$$

$$\Phi(x, y) = \sum_{i=1}^N C_i g_i(x, y)$$

$$\begin{aligned}g_1 &= 1 \\g_2 &= x \\g_3 &= -2r_A y + (2x^2 - y^2) \\g_4 &= -6r_A xy + x(2x^2 - 3y^2) \\g_5 &= -12r_A^2(x^2 - y^2) + 12r_A y(-4x^2 + y^2) + (8x^4 - 24x^2y^2 + 3y^4) \\g_6 &= -20r_A^2(x^3 - 3xy^2) + 20r_A xy(-4x^2 + 3y^2) + x(8x^4 - 40x^2y^2 + 15y^4) \\g_7 &= -40r_A^3(y^3 - 3yx^2) + 20r_A^2(-4x^4 + 21x^2y^2 - 3y^4) + \\&\quad + 30r_A y(-8x^4 + 12x^2y^2 - y^4) + (16x^6 - 120x^4y^2 + 90x^2y^4 - 5y^6).\end{aligned}$$



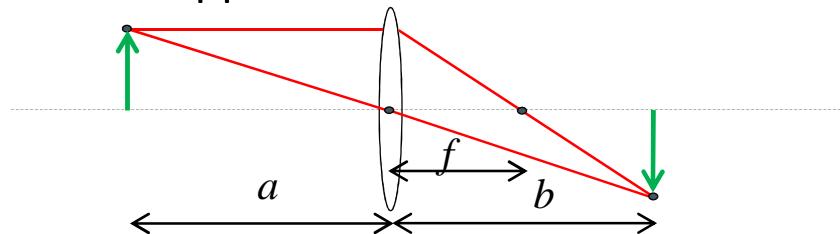
where $g_i(x, y)$ fulfill Laplace equation. The coefficients are fitted from the 4-8 nearest neighbor points with Singular Value Decomposition method. Weight of the points depends on the distance from the element center



Analogy with light optics

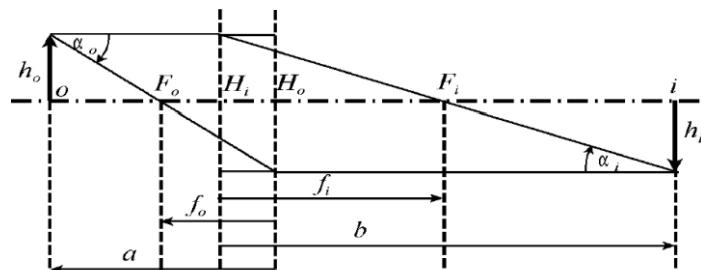
Basic phenomena of light optics valid in the charged particle optics

Thin lens approximation



$$\frac{1}{f} = \frac{1}{a} + \frac{1}{b}$$

But they are thick lenses



two main planes
in case of immersion lenses two focal lengths

$$\text{direct magnification } M = \frac{h_i}{h_o}$$

$$\text{angular magnification } M_\alpha = \frac{\alpha_i}{\alpha_o}$$



Solution of the equation of motion

Ordinary differential equation of the second order

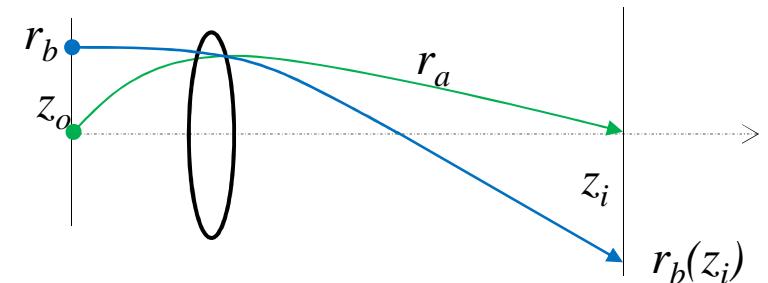
2 independent solutions for the initial conditions

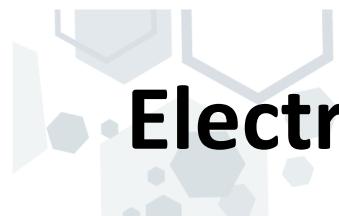
$$r_a(z_o) = 0, r'_a(z_o) = 1 \quad \Rightarrow \quad r_a(z_i) = 0, \quad r'_a(z_i) = M_a$$

$$r_b(z_o) = 1, r'_b(z_o) = 0 \quad \Rightarrow \quad r_b(z_i) = M \quad r'_b(z_i) = -\frac{1}{f_i}$$

Relationship between direct and angular magnification

$$\frac{\hat{\Phi}^{1/2}(z_i)}{\hat{\Phi}^{1/2}(z_o)} MM_a = 1$$

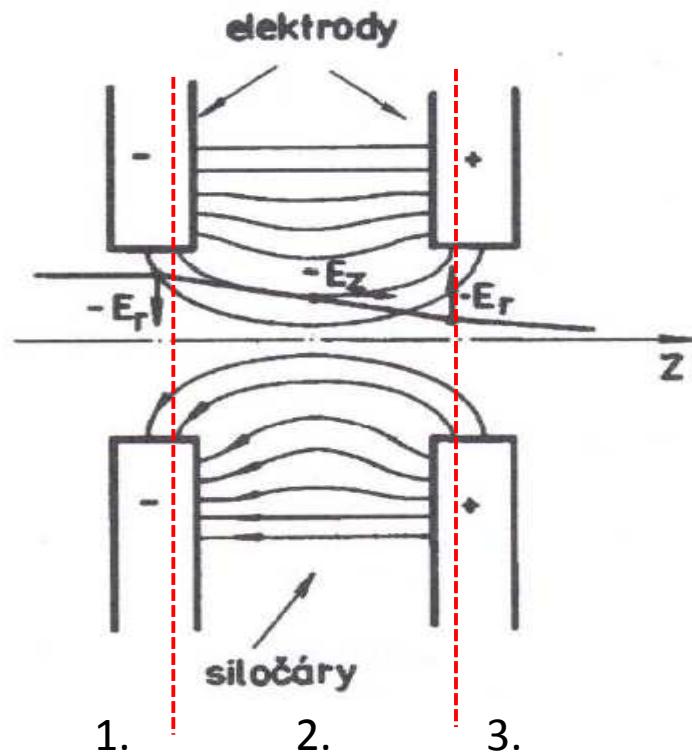




Electrostatic lens: how it focuses

1. Intensity E_r changes quickly, change of the radial velocity
2. Intensity E_z is constant, change of axial velocity
3. Smaller intensity $-E_r$, change of the radial velocity

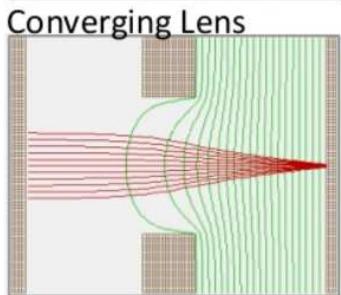
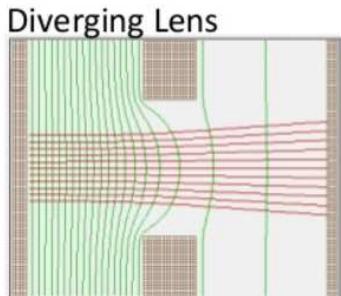
Axial symmetry of the fringe field causes linear focusing effect



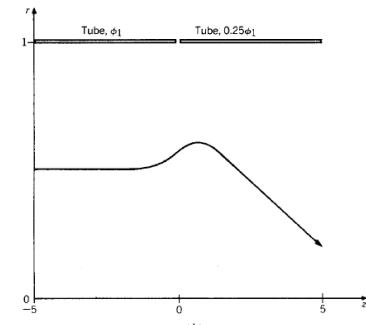
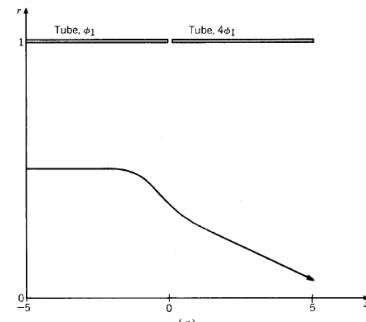


Electrostatic lenses

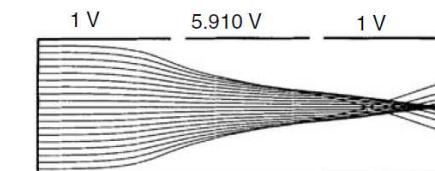
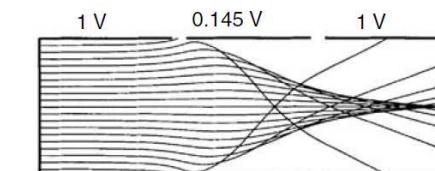
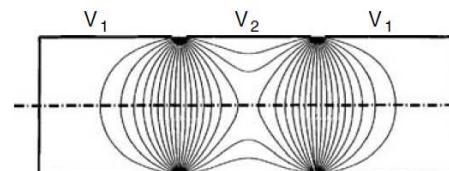
1 electrode lenses:
aperture lens



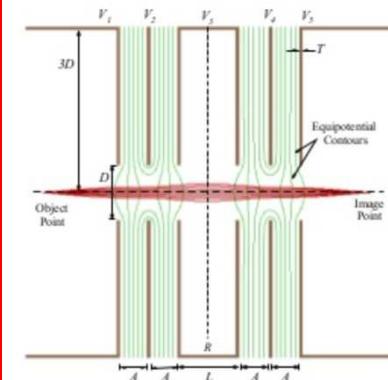
2 electrode lenses:
accelerating, decelerating



3 electrode lenses:
unipotential



4 and more
zoom lenses



Explore. Discover. Resolve.

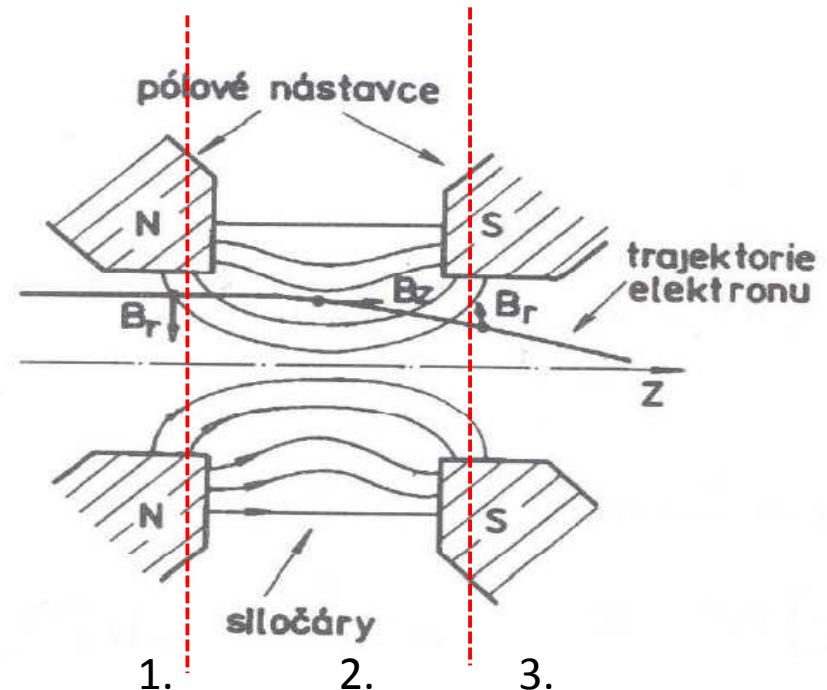
Vybrané partie z elektronové mikroskopie



Magnetostatic lens: how it focuses

1. Magnetic induction B_r changes quickly, a change of the tangential velocity
2. Magnetic induction B_z is constant, change of radial velocity
3. Magnetic induction B_r changes quickly, the tangential velocity stops

Axial symmetry of the fringe field causes linear focusing effect





Properties of magnetostatic lenses

First order properties

$$f = \frac{(s + d)k}{10 P (1 - P)} \quad P = \frac{(NI)^2}{300 \hat{\Phi}} \quad d = \frac{d_1 + d_2}{2}$$

Excitation parameter

$$exc = \frac{NI}{\sqrt{\hat{\Phi}}} \quad \text{scaling laws} \rightarrow \text{trajectories for same } exc \text{ same}$$

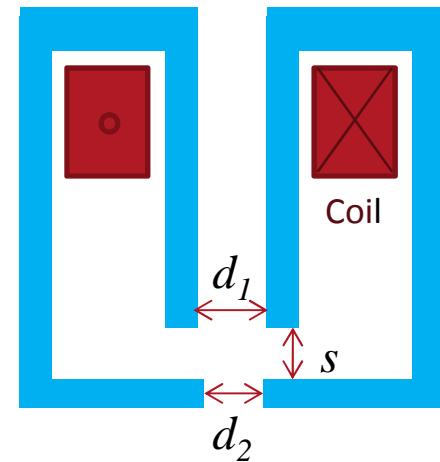
Rotation

$$\theta = \sqrt{\frac{|e|}{2m}} \int \frac{B_z(z)}{\sqrt{\hat{\Phi}}} dz$$

Axial aberrations

$$C_{si} \propto \frac{(1+|M|^4)f^3}{(s+d)d}$$

$$C_{ci} \propto (1 + |M|^2)f$$



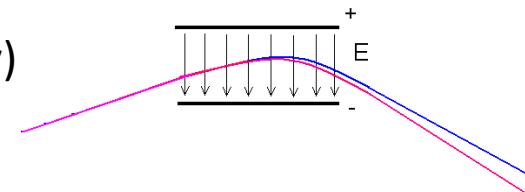


Properties of deflectors

Electrostatic (weak) perpendicular field: (parabolic trajectory)

Derivative of the movement

$$\frac{dx}{dz} = \frac{E_x l}{2\Phi}$$



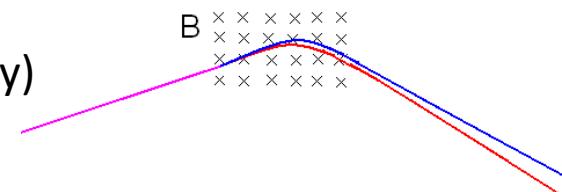
Deflection does not depend mass and charge – usage at focusing elements ion devices

FIB, SIMS

Magnetostatic (weak) perpendicular field: (circular trajectory)

Derivative of the movement

$$\frac{dy}{dz} = \frac{l}{R} = \frac{B_x}{\sqrt{\frac{2m\Phi}{e}}}$$



Deflection does depend on the mass and charge – filtering elements at ion devices

Weaker dependency on the particle energy – usage of transversal fields at accelerators



Deflectors

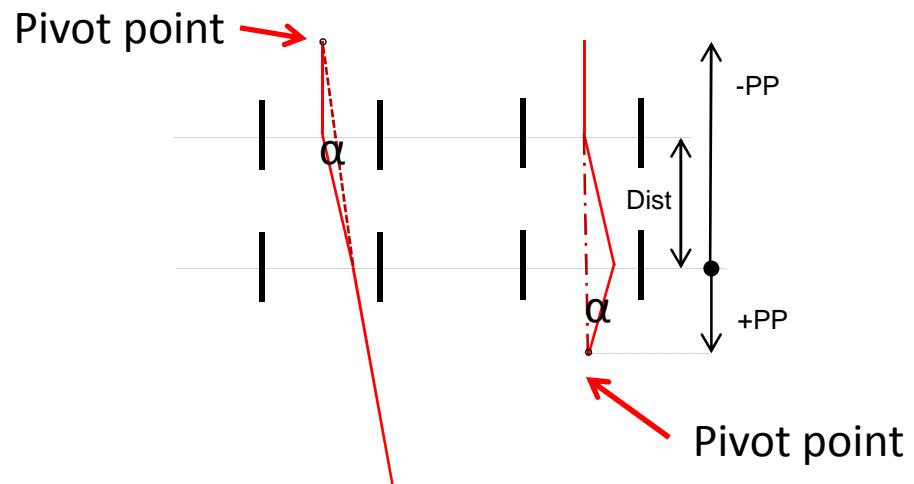
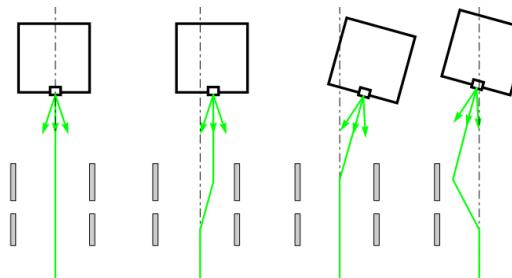
A pair of deflectors can manipulate with the beam

In the lateral position and angularly

$$Exc_{upper} \approx -\frac{\alpha \cdot PP}{Dist}$$

$$Exc_{lower} \approx \alpha \left(1 + \frac{PP}{Dist} \right)$$

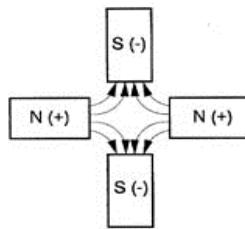
Pivot point is the position in the column where the beam rocks about





Properties of quadrupoles

Quadrupole multipole with $n=2$

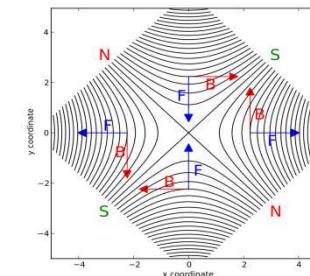


Forces on the charged particle

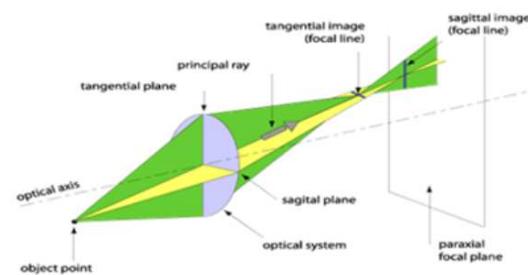
F_x independent of y position and proportional to x position

F_y independent of x position and proportional to y position

Field/forces on the axis is/are zero

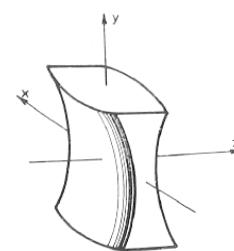


Usage as stigmator

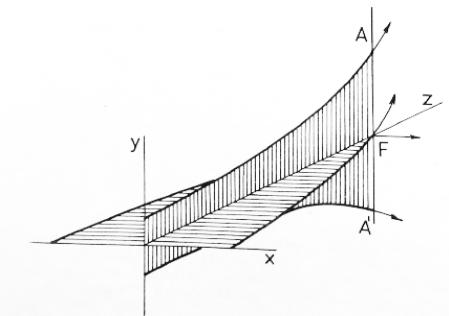


Explore. Discover. Resolve.

Light



Vybrané partie z elektronové mikroskopie





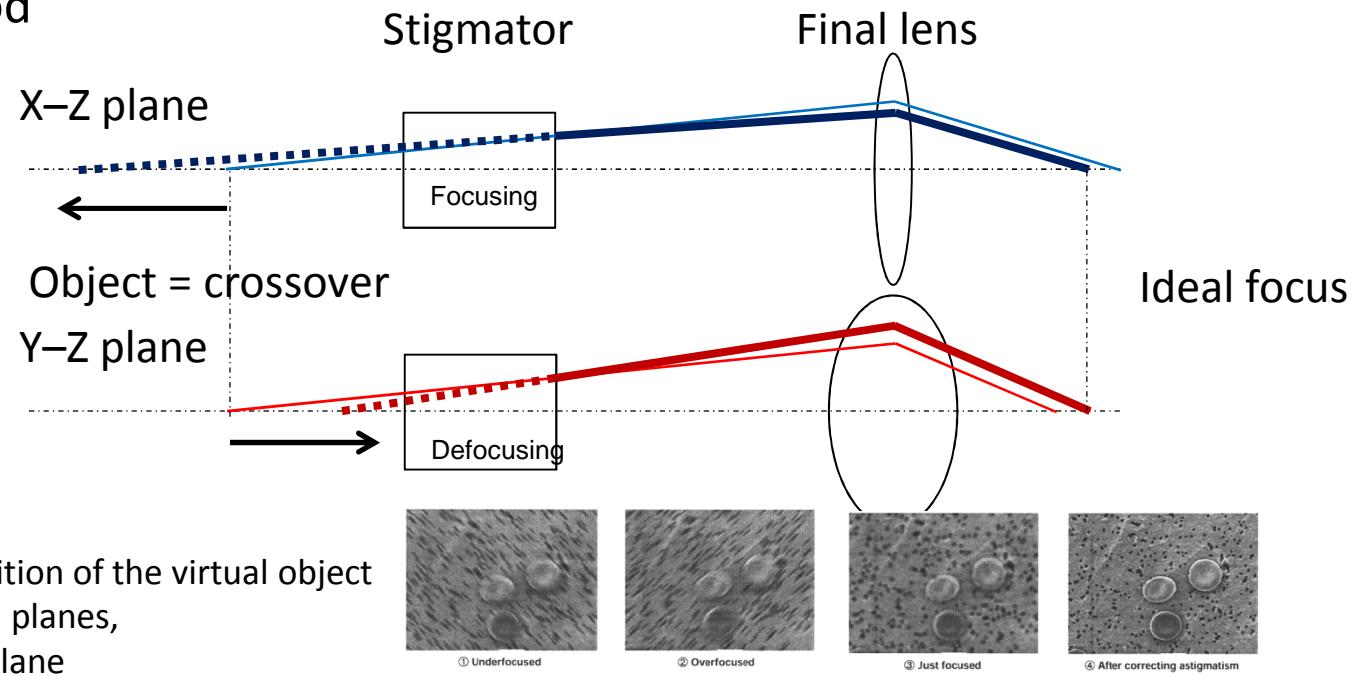
How stigmatation works

The final lens is not perfect: the focusing ability varies along the azimuthal angle with a π period

$$\frac{1}{f_x} = \sqrt{\kappa} \sin \sqrt{\kappa} L$$

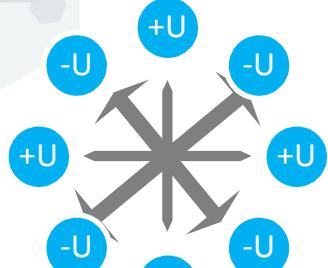
$$\frac{1}{f_y} = -\sqrt{\kappa} \sinh \sqrt{\kappa} L$$

The stigmator shifts the position of the virtual object differently in the orthogonal planes, depending linearly in each plane

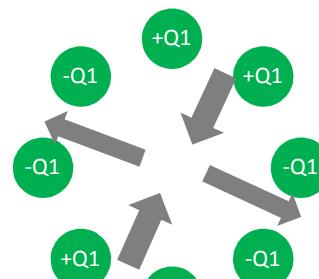




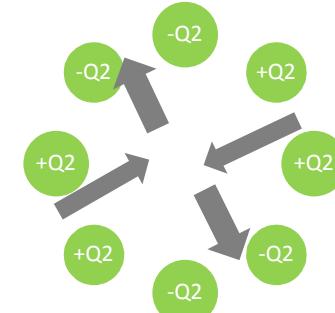
Multipoles



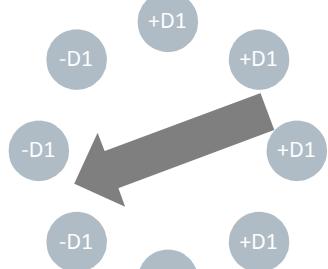
octupole



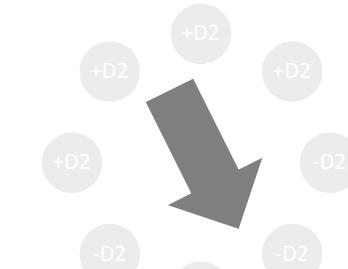
quadrupole 1



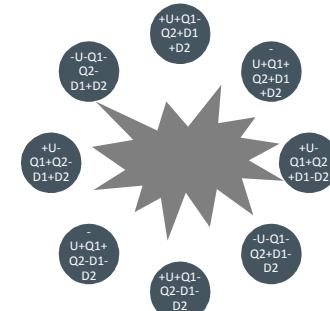
quadrupole 2



dipole 1



dipole 2



Superposition of all

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie



Scaling with Accelerating Voltage

- Equal trajectories if $\frac{E_z}{\Phi} = \text{const}$
- Equal trajectories if $\frac{B_z}{\sqrt{\hat{\Phi}}} = \text{const}$
- Particle mass depends on Φ ! Use relativistic corrected $\hat{\Phi}$

Consequences:

- Electrostatic field does not and magnetic field does split particles according mass and charge
- Permanent magnet effect $\propto \frac{1}{\sqrt{\hat{\Phi}}}$
- Charging effects $\propto \frac{1}{\Phi}$
- Geometrical misalignment effects do not depend on Φ
- Magnetic saturation effects at high Φ



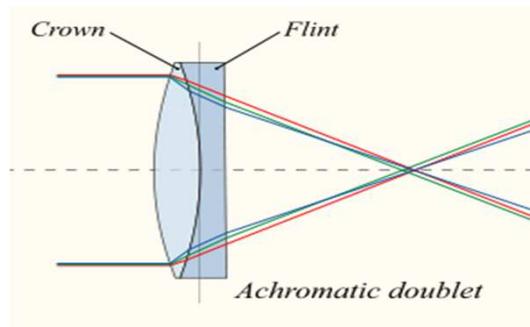
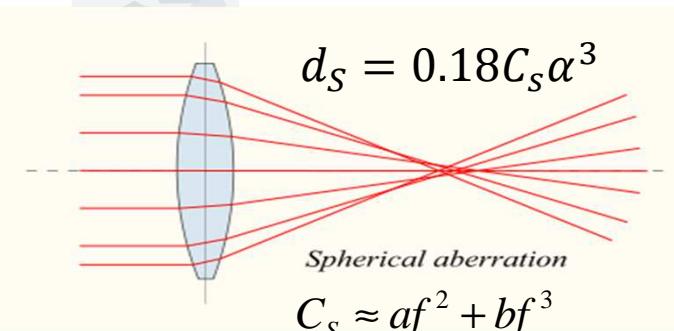
Aberrations

Aberrations cause blurring of an point source image

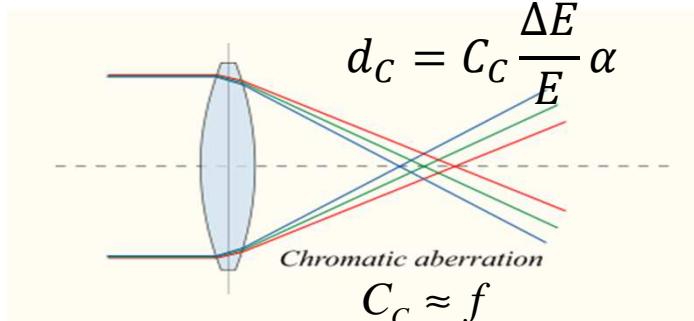
- Diffraction aberration due to wave character of particles
- Geometrical aberrations describing deviation from the linear behavior
- Chromatic aberrations due to finite energy width of the beam
- Parasitic aberrations ... stemming from the imperfection in
 - manufacturing
 - bad alignment
 - instabilities of HT and power supplies
 - thermal drift of the column assemblies
 - lack of homogeneity of the lens materials



Axial aberrations



Correction not possible in charged particle optics in such an easy way



Scherzer's theorem (1936)

Electromagnetic lenses have unavoidable aberrations (spherical and chromatic) as long as the following conditions are fulfilled:

- Lens fields are rotationally symmetric → multipoles
- The electromagnetic fields are static → RF operation
- There is no space charges → electron mirrors



Aberrations

Deviation of the real wavefront from the ideal one

Aberration function

With the length dimension [m, μm , ...]

Dependent on the radial angle θ and azimuthal angle ϕ

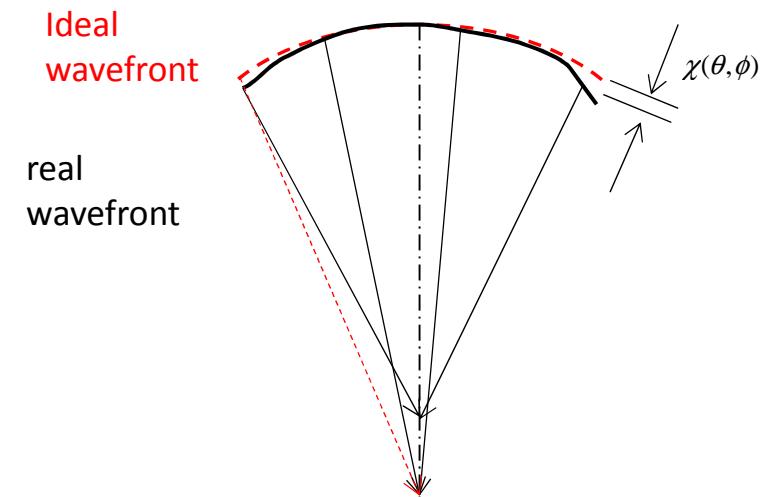
Precision needed $\lambda/4 \sim 1\text{pm}$

Relative precision \sim deviation of the wavefront / diameter of the wavefront in the objective ...i.e. $1\text{pm}/100\mu\text{m} = 10^{-12}/10^{-4} = 10^{-8}$

Comparable with modern astronomical telescopes

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie





Aberrations

Representation of geometrical aberration function Křivánek, Delby & Lupini

$$\chi(\theta, \phi) = \sum_n \sum_m \{ C_{n,m,a} \theta^{n+1} \cos(m\phi) + C_{n,m,b} \theta^{n+1} \sin(m\phi) \} / (n+1)$$

Where

θ ... semiangle $\in 0 \div \sim 50$ mrad

ϕ ... azimuthal angle $\in 0 \div 2\pi$

n ... order $\in 0 \div 7$

m ... multiplicity $\in 0 \div 6$

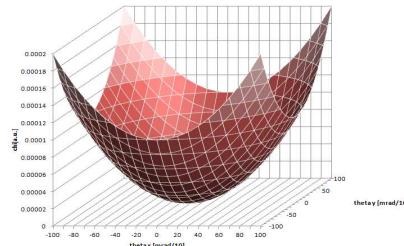
For odd n even $m = 0, 2, 4 \dots n+1$ e.g. $C_{1,0}; C_{1,2}; C_{3,0}; C_{5,2}$

For even n odd $m = 1, 3, 5 \dots n+1$ e.g. $C_{0,1}; C_{2,1}; C_{2,3}; C_{4,5}$

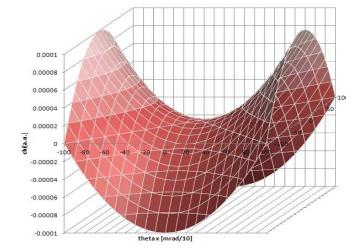
For $m=0$ no azimuthal dependence is no term $C_{n,0,b}$ e.g. $C_{3,0}$



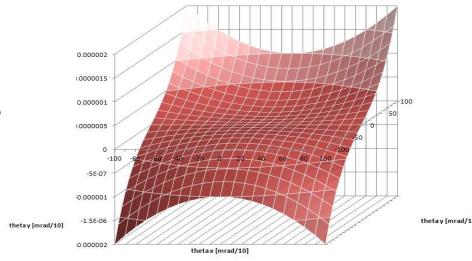
Wavefront errors



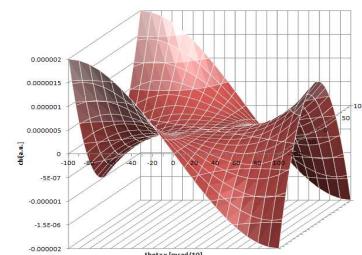
Defocus $C_{1,0}$



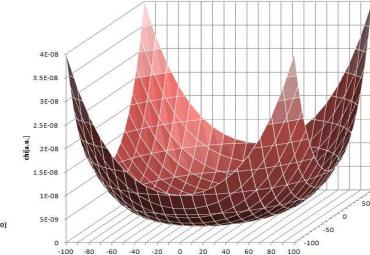
Astigmatism $C_{1,2,a}$



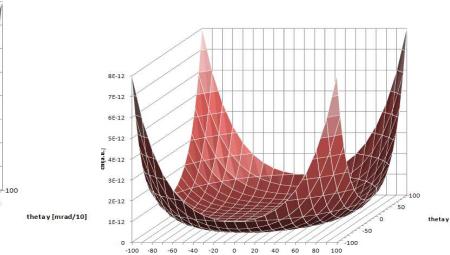
Axial coma $C_{2,1,b}$



3-f Astigmatism $C_{2,3,a}$



Spherical aberr.C_{3,0}



Spherical aberr.C_{5,0}

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie



Resolution at scanning probe systems

Resolution depends on:

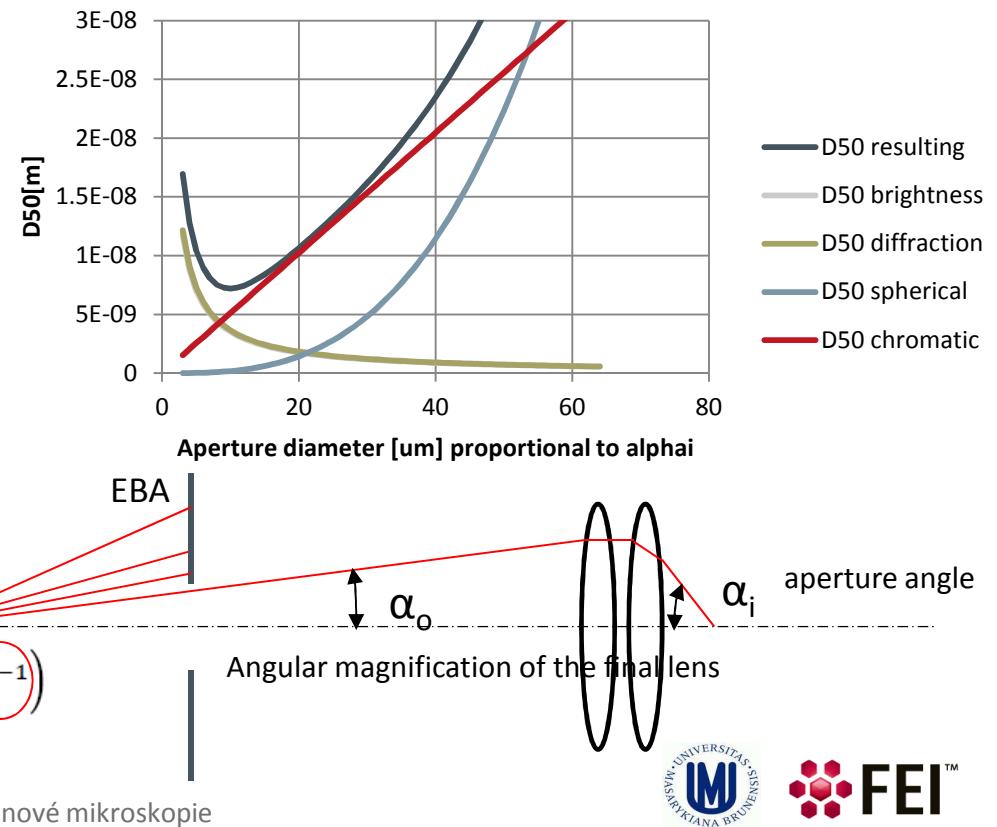
- Spherical axial aberration
- Chromatic axial aberration
- Diffraction aberration
- Spot size influence by the brightness
- Coulomb interactions
- Many other effects...noise, vibrations, stray magnetic field

$$d^2 = \left[\left(d_S^4 + d_D^4 \right)^{\frac{1}{4}} + d_G^{1.3} \right]^{2/1.3} + d_C^2$$

$$d_S = K_S C_S \alpha^3, d_C = K_C C_C \frac{d\phi}{\phi} \alpha, d_D = K_D \lambda \alpha^{-1}, d_G = M d_0$$

$$K_S = 0.18, K_C = 0.34, K_D = 0.54$$

$$\left(d_G = \left(\frac{4I_p}{\pi i^2 \beta} \right)^{1/2} \alpha^{-1} \right)$$



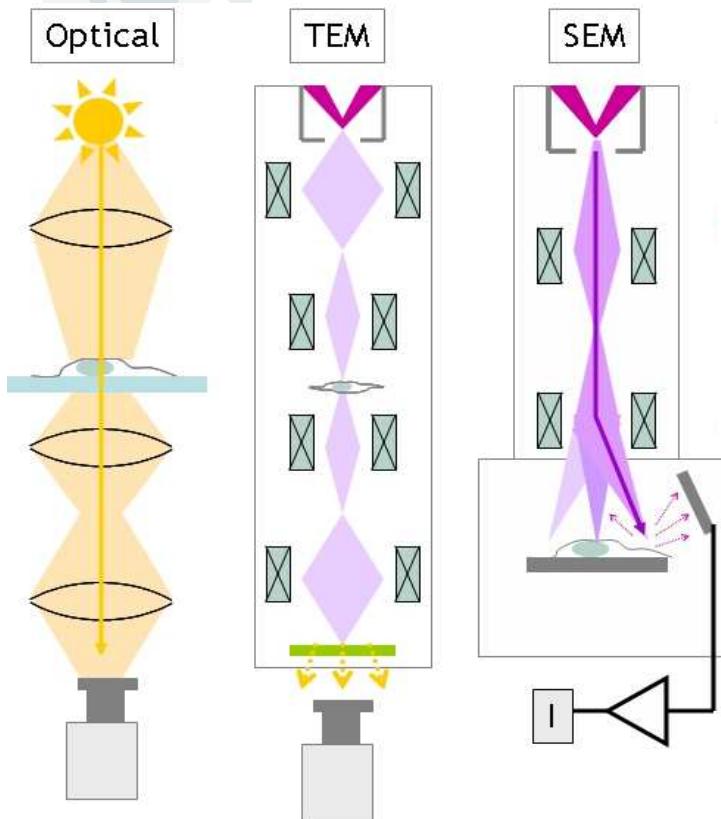
Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie





Image creation



Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie

Full field systems

Advantages:

- traditional approach,
- image instantaneously available
- high resolution due to optics

Disadvantages:

- more complex, more expensive
- pixelated detectors
- complicated specimen preparation

Scanning probe systems:

Advantages:

- simpler, cheaper, for any specimens
- integral detectors for various signals

Disadvantages:

- image not present at one instant
- resolution due to scanning



State of the art SEM: general specifications

Parameter	Value(s)	
Landing energy	20 ÷ 30000 eV	<i>~3 orders of magnitude</i>
Probe current	0.78 pA ÷ 410 nA	<i>~6 orders of magnitude</i>
Maximum/minimum field of view	3 mm / 50 nm	<i>~6 orders of magnitude</i>
Resolution	<1 nm	
Beam current control	Continuous	
Vacuum modes	Hi Vac ($\sim 10^{-4}$ Pa), Low Vac (10-50 Pa)	



Scanning electron microscope

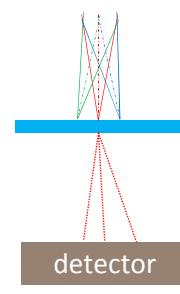
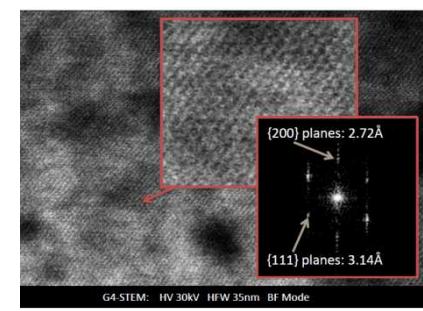
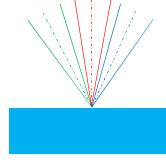
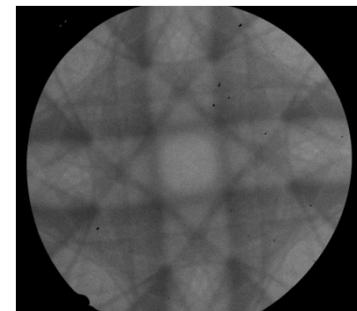
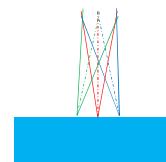
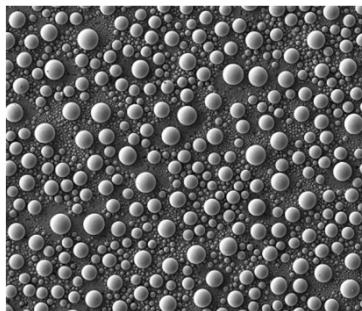
Different modes

Full frame, Line, Spot, Pattern

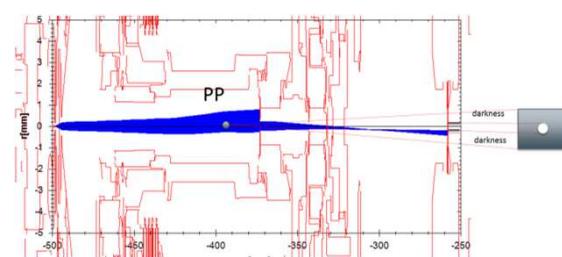
Channeling contrast

STEM

Imaging



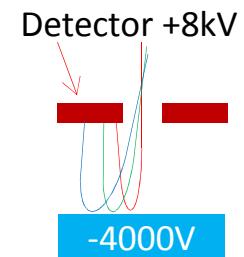
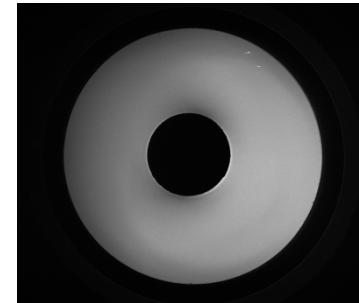
Diagnostics



Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie

Mirror





Scanning electron microscope

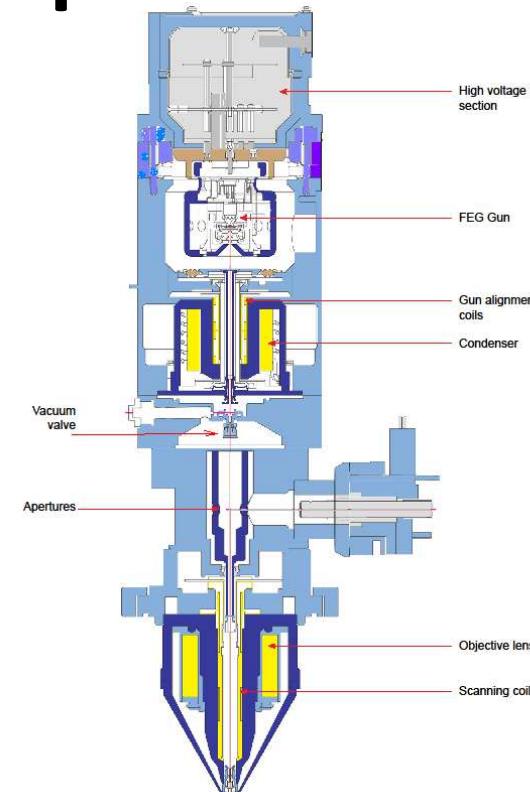
- Electron or ion source
- Lenses
- Mechanical alignment
- Alignment deflectors
- Scanning deflectors
- Stigmators
- Apertures
- Magnetic shielding
- Vacuum 10^{-4} to 10^{-8} Pa
- Differential pumping
- Mechanical stiffness, vibration and acoustic resistance
- Drifts
- Detectors
- Stable sources
- Alignments
- Control model and SW

Explore. Discover. Resolve.

linear device

10^{-4} to 10^{-8} Pa

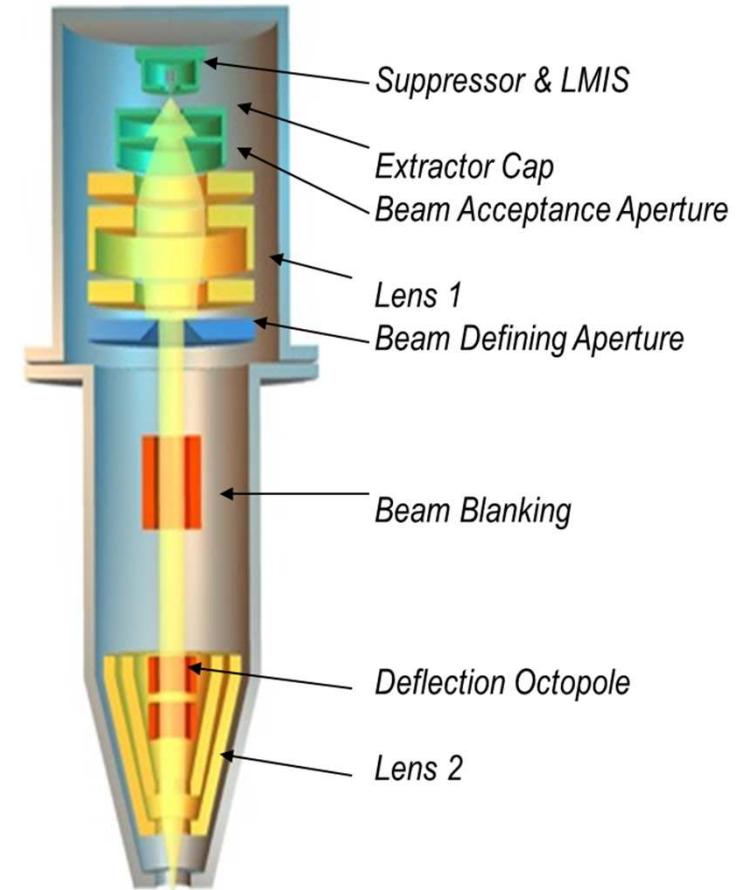
Vybrané partie z elektronové mikroskopie





Ion Columns

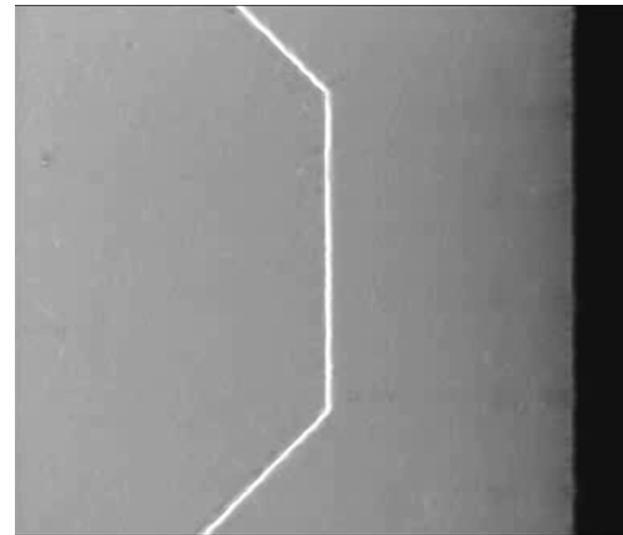
- Various sources and species: Ga, In, Li, He, Ar
- Electrostatic elements
- Coulomb interactions crucial for resolution
- Sputtering of apertures
- Higher sensitivity on vacuum – beam sputtering
- Micromachining and Gas-assisted etching
- Destructive method
- Volume sputtered is independent of the scan field





Workflow for electronic industry

1. Select the region of interest
2. Dig out the material in the vicinity
3. Form the lamella, cut on one side
4. Approach the needle
5. Weld the needle and lamella, cut the lamella
6. Transport the lamella to special holder, weld it
7. Cut the needle, repolish the lamella to ~20nm
8. Transport to TEM



Explore. Discover. Resolve.

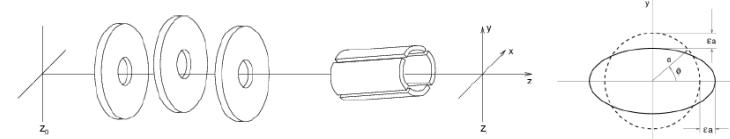
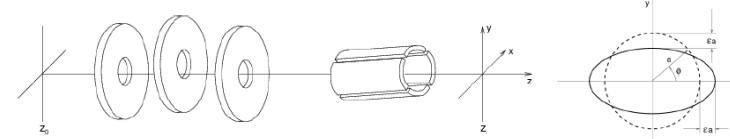
Vybrané partie z elektronové mikroskopie





Design issues

- Colinearity and circularity of the optical elements better in sub- μm region
- Assembling of heavy parts with micron precision – different systems for mechanical alignment: kinematical mounting (cone, prism & plane), deformable string of balls + V grooves
- Vacuum issues:
 - usage of a liner – thin non magnetic tube – excludes electrostatics
 - absence of a liner implies usage of vacuum sealed magnetostatic lenses
 - pressure gradient from the chamber up to the electron gun – differential pumping

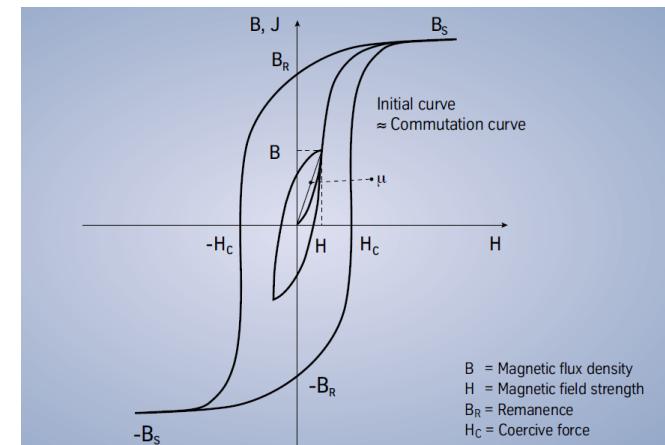


Electrostatic lenses

- Electrostatic breakdown on the electrostatic lenses: vacuum 10kV/mm, surface much less – rounded shapes of the insulators: ruby balls, PEEK, Macor, ceramics

Design

- Saturation in the yokes of the magnetostatic lenses: design, high saturation soft magnetic materials: ARMCO iron (pure annealed Fe 2.15 T), permalloy (48% Ni and Fe)
 - Remanence – degaussing rigorous but lengthy normalization easier
 - Soft magnetic material turned before and after annealing
 - Mechanical strain destroys the ferromagnetic properties
 - Thermal load of the magnetostatic lenses due to the Joule heating water cooling ~ 1000 W – vibrations, drifts



Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie





Design issues

Design constraints results in the physical dimensions of the lenses

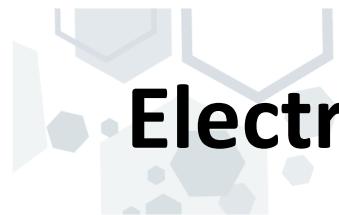
Magnification in the full field view systems obtained by ratios of object and image distance → TEM length ~ 3 m : condenser + objective + projective

Scanning probe system more length effective ~ 0.5 m: condenser + final lens

Charging of the materials

Almost all design materials are covered with thin semi or non conductive oxide layer

Solution: covering with carbon



Electrostatic versus Magnetic

	Electrostatic	Magnetostatic
Drivers	High voltage	High currents
Environment	Vacuum	Non magnetic
Column heating	no	yes
Scaling with beam energy	$\sim HV$	$\sim HV^{1/2}$
Scaling with particle mass	no	$\sim m^{1/2}$
Speed	Faster	Slower
Accuracy	High	Lower (hysteresis)
Cost	More expensive	Less expensive
Application area	Ion optics Low energy electrons Fast systems (beam blanker, lithography)	High energy electrons (TEM) Low cost systems

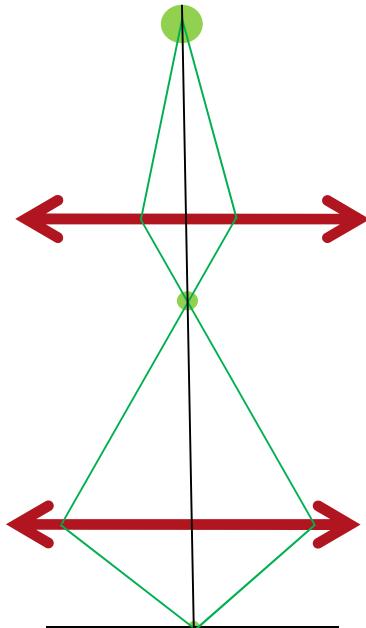
Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie

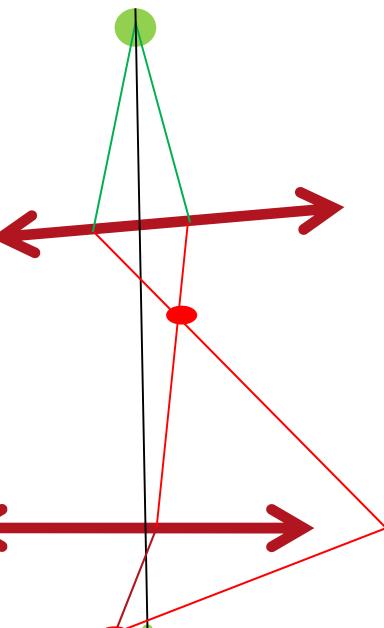


Alignments

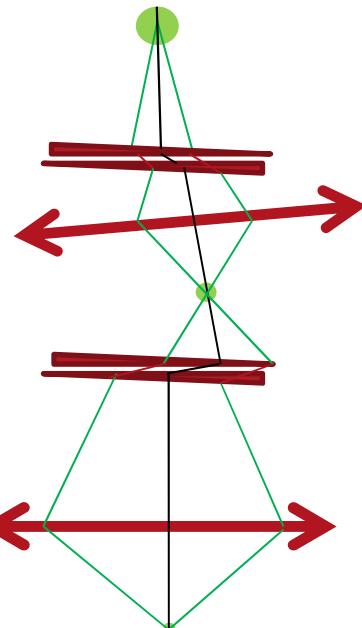
Ideal system



Real system



Aligned real system



Pairs of deflectors are mostly used for alignments. The position of the pivot point defines their usage. Deflections with different pivot points can be added thanks to linearity.

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie



Thank you for your attention

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie





Further reading

- M. Lenc, B. Lencová: Optické prvky elektronových mikroskopů
Metody analýzy povrchů 2. Elektronová mikroskopie a difrakce.
(L. Eckertová, L. Frank ed.) Academia 1996
- B. Lencová, M. Lenc: Optika iontových svazků. Metody analýzy povrchů 3.
(L Frank, J.Král, ed.), Academia 2002
- L. Reimer, Scanning Electron Microscopy -- Physics of Image Formation and Microanalysis,
Springer-Verlag 1998
- J. Orloff, ed. Handbook of Charged Particle Optics, CRC Press, 2nd edition 2008
- P. W Hawkes, E. Kasper: Principles of electron optics, vol. 1-3. Academic 1988 and 1996



Determination of the field in 3D

Finite differences method (FDM ... Simion)

Advantages: easy to program

Disadvantage: not precise enough

Finite elements method (FEM ... MEBS, CST, Comsol + open source...)

Advantages: covers any geometry, non-linearities, commercial packages

Disadvantage: Precise field values only on the nodes, rest
interpolated, evaluation of the higher order derivatives
restriction to the modeled space

Boundary element method (BEM ... Lorentz, open source)

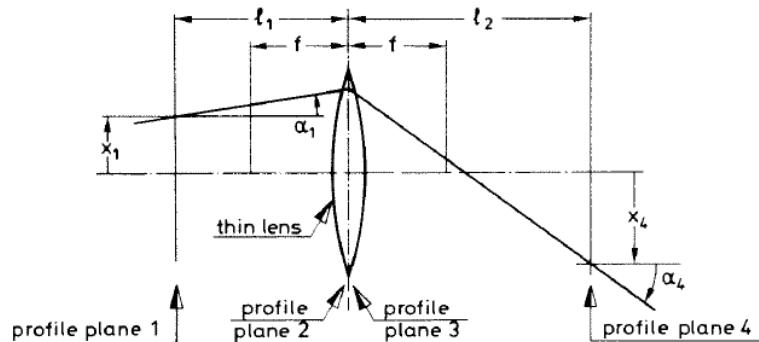
Advantages: reduces dimensionality of the task by 1, precise field,
any geometry, suitable for semi-infinite space

Disadvantages: not suitable for non-linear material properties



Transfer matrix method

Thin lens approximation



$$\begin{pmatrix} x_4 \\ \tan \alpha_4 \end{pmatrix} = \begin{pmatrix} 1 & l_2 \\ 0 & 1 \end{pmatrix} \begin{pmatrix} 1 & 0 \\ -1/f & 1 \end{pmatrix} \begin{pmatrix} 1 & l_1 \\ 0 & 1 \end{pmatrix} \begin{pmatrix} x_1 \\ \tan \alpha_1 \end{pmatrix}$$

Explore. Discover. Resolve.

Vybrané partie z elektronové mikroskopie

Drift space

$$\begin{bmatrix} x_2 \\ x'_2 \\ 1 \end{bmatrix} = \begin{bmatrix} 1 & L & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} x_1 \\ x'_1 \\ 1 \end{bmatrix}$$

Lens

$$\begin{bmatrix} x_2 \\ x'_2 \\ 1 \end{bmatrix} = \begin{bmatrix} 1 & 0 & 0 \\ -\frac{1}{f} & 1 & 0 \\ 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} x_1 \\ x'_1 \\ 1 \end{bmatrix}$$

Deflector

$$\begin{bmatrix} x_2 \\ x'_2 \\ 1 \end{bmatrix} = \begin{bmatrix} 1 & 0 & 0 \\ 0 & 1 & \frac{IB_0\eta}{\sqrt{\Phi}} \\ 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} x_1 \\ x'_1 \\ 1 \end{bmatrix}$$

$$f = \frac{(s+d)k}{10 P (1-P)}$$

$$P = \frac{(NI)^2}{300 \hat{\Phi}}$$